Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: | |
|--|--|
| Metal | |
| Overall Length: | |
| 2.845 inches | |
| Overall Height: | |
| 0.670 inches | |
| Overall Width: | |
| 0.890 inches | |
| End Application: | |
| B-1b | |
| Mounting Facility Quantity: | |
| 2 | |
| Mounting Method: | |
| Unthreaded hole | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| 36.0 breakdown voltage, instantaneous | |
| Current Rating Per Characteristic: | |
| 300.00 amperes forward current, average preset | |
| Power Rating Per Characteristic: | |
| 10.0 watts small-signal input power, common-collector preset | |
| Terminal Type And Quantity: | |
| 2 turret | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |